Product data sheet

1. General description

The 74LVC30A is an 8-input NAND gate.

Inputs can be driven from either 3.3~V or 5~V devices. This feature allows the use of these devices in a mixed 3.3~V and 5~V environment.

Schmitt trigger action at all inputs makes the circuit tolerant for slower input rise and fall time.

This device is fully specified for partial power-down applications using I_{OFF} . The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

2. Features and benefits

- Wide supply voltage range from 1.2 V to 3.6 V
- Inputs accept voltages up to 5.5 V
- CMOS low power consumption
- Direct interface with TTL levels
- Complies with JEDEC standard:
 - JESD8-7A (1.65 V to 1.95 V)
 - JESD8-5A (2.3 V to 2.7 V)
 - JESD8-C/JESD36 (2.7 V to 3.6 V)
- ESD protection:
 - HBM JEDEC JS-001-2012 exceeds 2000 V
 - MM JESD22-A115-C exceeds 200 V
 - CDM JESD22-C101F exceeds 1000 V
- Specified from -40 °C to +85 °C and -40 °C to +125 °C



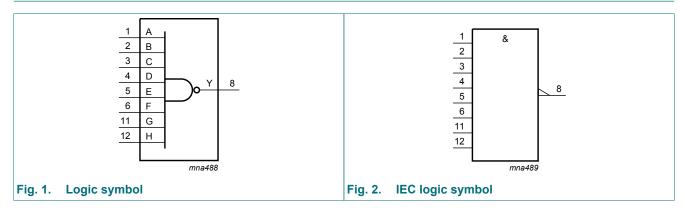
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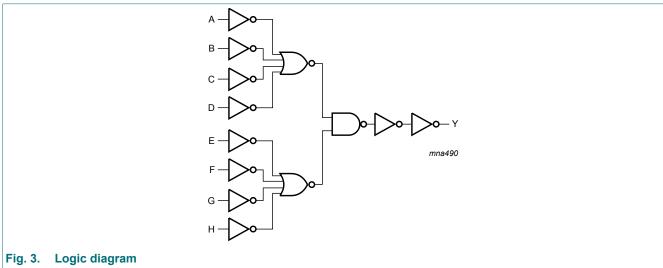
3. Ordering information

Table 1. Ordering information

Type number	Package						
	Temperature range Name Description		Description	Version			
74LVC30AD	-40 °C to +125 °C	SO14	plastic small outline package; 14 leads; body width 3.9 mm	SOT108-1			
74LVC30APW	-40 °C to +125 °C	TSSOP14	plastic thin shrink small outline package; 14 leads; body width 4.4 mm	SOT402-1			
74LVC30ABQ	-40 °C to +125 °C	DHVQFN14	plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 14 terminals; body 2.5 x 3 x 0.85 mm	SOT762-1			

4. Functional diagram

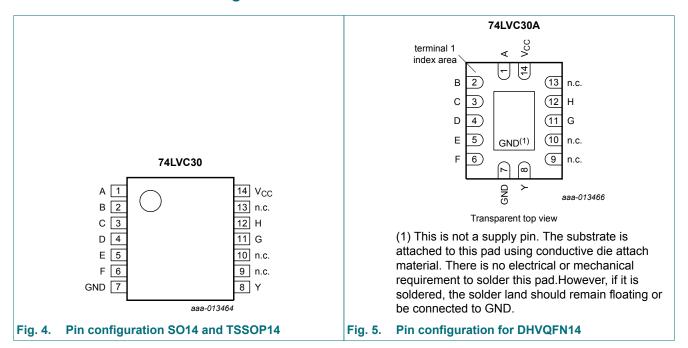




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5. Pinning information

5.1. Pinning



5.2. Pin description

Table 2. Pin description

Table 2.1 III description				
Symbol	Pin	Description		
A, B, C, D, E, F, G, H	1, 2, 3, 4, 5, 6, 11, 12	data input		
GND	7	ground (0 V)		
Υ	8	data output		
n.c.	9, 10, 13	not connected		
V _{CC}	14	supply voltage		

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6. Functional description

Table 3. Function table

 $H = HIGH \ voltage \ level; \ L = LOW \ voltage \ level; \ X = don't \ care.$

Input	nput					Output		
Α	В	С	D	E	F	G	Н	Y
L	Х	Х	Х	Х	Х	Х	Х	Н
Χ	L	Х	Х	Х	Х	Х	Х	Н
Χ	Х	L	Х	Х	Х	Х	Х	Н
Χ	Х	Х	L	Х	Х	Х	Х	Н
Χ	Х	Х	Х	L	Х	Х	Х	Н
X	Х	Х	Х	Х	L	Х	Х	Н
Χ	Х	Х	Х	Х	Х	L	Х	Н
Χ	Х	Х	Х	Х	Х	Х	L	Н
Н	Н	Н	Н	Н	Н	Н	Н	L

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _{CC}	supply voltage			-0.5	+6.5	V
I _{IK}	input clamping current	V _I < 0 V		-50	-	mA
VI	input voltage		[1]	-0.5	+6.5	V
I _{OK}	output clamping current	$V_O > V_{CC}$ or $V_O < 0$ V		-	±50	mA
V _O	output voltage		[2]	-0.5	V _{CC} + 0.5	V
Io	output current	$V_O = 0 V \text{ to } V_{CC}$		-	±50	mA
I _{CC}	supply current			-	100	mA
I _{GND}	ground current			-100	-	mA
P _{tot}	total power dissipation	T _{amb} = -40 °C to +125 °C	[3]	-	500	mW
T _{stg}	storage temperature			-65	+150	°C

^[1] The minimum input voltage ratings may be exceeded if the input current ratings are observed.

8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{CC}	supply voltage		1.65	-	3.6	V
		functional	1.2	-	-	V
VI	input voltage		0	-	5.5	V
Vo	output voltage	Active mode	0	-	V _{CC}	V
		V _{CC} = 0 V; Power-down mode	0	-	5.5	V

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^[2] The output voltage ratings may be exceeded if the output current ratings are observed.

^[3] For SO14 packages: above 70 °C the value of P_D derates linearly with 8 mW/K.
For TSSOP14 packages: above 60 °C the value of P_D derates linearly with 5.5 mW/K.
For DHVQFN14 packages: above 60 °C the value of P_D derates linearly with 4.5 mW/K.

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
T _{amb}	ambient temperature	in free air	-40	-	+125	°C
Δt/ΔV	input transition rise and	V _{CC} = 1.65 V to 2.7 V	0	-	20	ns/V
	fall rate	V _{CC} = 2.7 V to 3.6 V	0	-	10	ns/V

9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40 °C to +85 °C			-40 °C to	Unit	
			Min	Typ[1]	Max	Min	Max	
V _{IH}	HIGH-level input	V _{CC} = 1.2 V	1.08	-	-	1.08	-	V
	voltage	V _{CC} = 1.65 V to 1.95 V	0.65 × V _{CC}	-	-	0.65 × V _{CC}	-	V
		V _{CC} = 2.3 V to 2.7 V	1.7	-	-	1.7	-	V
		V _{CC} = 2.7 V to 3.6 V	2.0	-	-	2.0	-	V
V _{IL}	LOW-level input	V _{CC} = 1.2 V	-	-	0.12	-	0.12	V
	voltage	V _{CC} = 1.65 V to 1.95 V	-	-	0.35 × V _{CC}	-	0.35 × V _{CC}	٧
		V _{CC} = 2.3 V to 2.7 V	-	-	0.7	-	0.7	V
		V _{CC} = 2.7 V to 3.6 V	-	-	0.8	-	0.8	V
V _{OH}	HIGH-level	$V_I = V_{IH}$ or V_{IL}						
C	output voltage	I _O = -100 μA; V _{CC} = 1.65 V to 3.6 V	V _{CC} - 0.2	-	-	V _{CC} - 0.3	-	V
		I _O = -4 mA; V _{CC} = 1.65 V	1.2	-	-	1.05	-	٧
		I _O = -8 mA; V _{CC} = 2.3 V	1.8	-	-	1.65	-	V
		I _O = -12 mA; V _{CC} = 2.7 V	2.2	-	-	2.05	-	V
		I _O = -18 mA; V _{CC} = 3.0 V	2.4	-	-	2.25	-	V
		I _O = -24 mA; V _{CC} = 3.0 V	2.2	-	-	2.0	-	V
V _{OL}	LOW-level output voltage	V _I = V _{IH} or V _{IL}						
		I _O = 100 μA; V _{CC} = 1.65 V to 3.6 V	-	-	0.2	-	0.3	V
		I _O = 4 mA; V _{CC} = 1.65 V	-	-	0.45	-	0.65	٧
		$I_O = 8 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.6	-	0.8	V
		I_{O} = 12 mA; V_{CC} = 2.7 V	-	-	0.4	-	0.6	V
		I_{O} = 24 mA; V_{CC} = 3.0 V	-	-	0.55	-	0.8	V
l _l	input leakage current	$V_{CC} = 3.6 \text{ V}; V_I = 5.5 \text{ V or GND}$	-	±0.1	±5	-	±20	μΑ
I _{OFF}	power-off leakage current	$V_{CC} = 0 \text{ V}; V_{I} \text{ or } V_{O} = 5.5 \text{ V}$	-	±0.1	±10	-	±20	μΑ
I _{CC}	supply current	$V_{CC} = 3.6 \text{ V}; V_{I} = V_{CC} \text{ or GND}; I_{O} = 0 \text{ A}$	-	1	10	-	40	μΑ
ΔI _{CC}	additional supply current	per input pin; $V_{CC} = 2.7 \text{ V to } 3.6 \text{ V};$ $V_{I} = V_{CC} - 0.6 \text{ V};$ $I_{O} = 0 \text{ A}$	-	5	500	-	5000	μΑ
C _I	input capacitance	V_{CC} = 0 V to 3.6 V; V_{I} = GND to V_{CC}	-	4.0	-	-	-	pF

^[1] All typical values are measured at V_{CC} = 3.3 V (unless stated otherwise) and T_{amb} = 25 °C.

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10. Dynamic characteristics

Table 7. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V). For test circuit, see Fig. 7.

Symbol	Parameter	Conditions		-40 °C to +85 °C		5 °C	-40 °C to	+125 °C	Unit
				Min	Typ[1]	Max	Min	Max	1
t _{pd}	propagation delay	A, B, C, D, E, F, G, H to Y; see Fig. 6	2]						
		V _{CC} = 1.2 V		-	13.2	-	-	-	ns
		V _{CC} = 1.65 V to 1.95 V		2.2	5.9	11.6	2.2	12.3	ns
		V _{CC} = 2.3 V to 2.7 V		1.6	3.9	7.3	1.6	7.9	ns
		V _{CC} = 2.7 V		1.5	4.1	7.3	1.5	7.8	ns
		V _{CC} = 3.0 V to 3.6 V		1.4	3.6	6.3	1.4	6.8	ns
C _{PD}	power dissipation	per gate; V _I = GND to V _{CC}	3]						
	capacitance	V _{CC} = 1.65 V to 1.95 V		-	12.5	-	-	-	pF
		V _{CC} = 2.3 V to 2.7 V		-	13.5	-	-	-	pF
		V _{CC} = 3.0 V to 3.6 V		-	15.5	-	-	-	pF

Typical values are measured at T_{amb} = 25 °C and V_{CC} = 1.2 V, 1.8 V, 2.5 V, 2.7 V, and 3.3 V respectively.

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}^2 \times f_o)$$
 where:

 f_i = input frequency in MHz;

 f_o = output frequency in MHz;

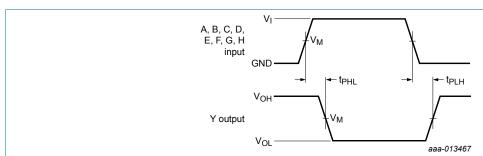
C_L = output load capacitance in pF;

V_{CC} = supply voltage in Volt;

N = number of inputs switching;

 $\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

10.1. Waveform and test circuit



 $V_M = 1.5 \text{ V at } V_{CC} \ge 2.7 \text{ V}$

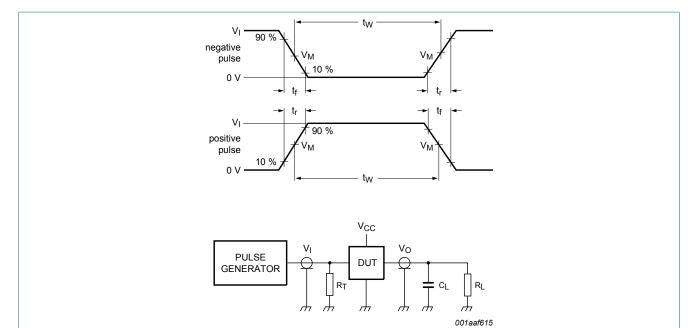
 $V_M = 0.5 \times V_{CC}$ at $V_{CC} < 2.7 \text{ V}$.

V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Input (A, B, C, D, E, F, G, H) to output (Y) propagation delays

 t_{pd} is the same as t_{PLH} and t_{PHL} . C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

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Test data is given in Table 8.

Definitions for test circuit:

 R_L = Load resistance.

 C_L = Load capacitance including jig and probe capacitance.

 R_T = Termination resistance should be equal to output impedance Z_0 of the pulse generator.

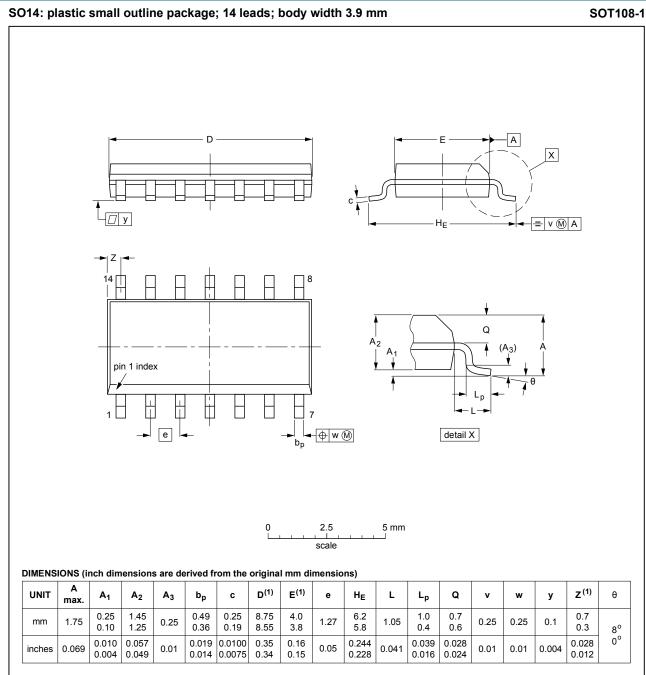
Fig. 7. Test circuit for measuring switching times

Table 8. Test data

Supply voltage	Input	Input		
	VI	t _r , t _f	CL	R _L
1.2 V	V _{CC}	≤ 2 ns	30 pF	1 kΩ
1.65 V to 1.95 V	V _{CC}	≤ 2 ns	30 pF	1 kΩ
2.3 V to 2.7 V	V _{CC}	≤ 2 ns	30 pF	500 Ω
2.7 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω
3.0 V to 3.6 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω

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11. Package outline



Note

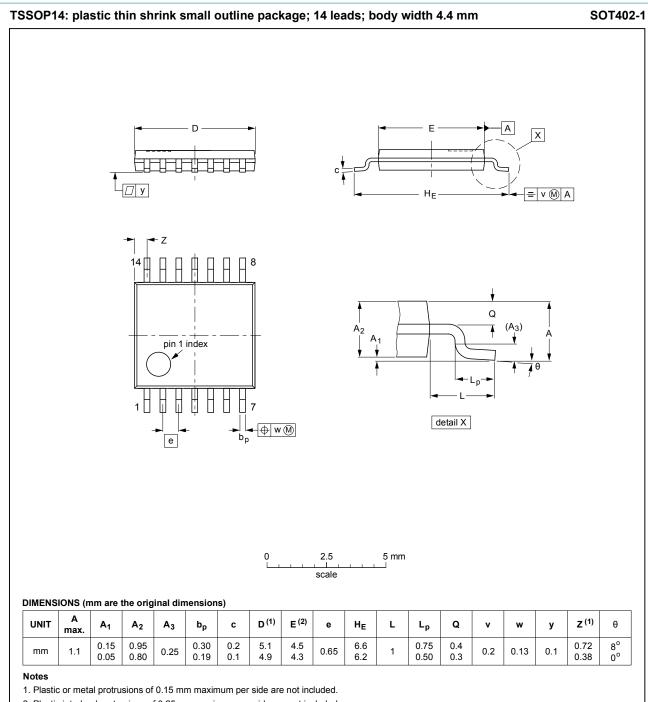
1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	ENCES	EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT108-1	076E06	MS-012			99-12-27 03-02-19

Fig. 8. Package outline SOT108-1 (SO14)

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2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	ENCES	EUROPEAN ISSUE DATE	
VERSION	IEC	JEDEC	JEITA	PROJECTION ISSUE DATE	ISSUE DATE
SOT402-1		MO-153			99-12-27 03-02-18

Fig. 9. Package outline SOT402-1 (TSSOP14)

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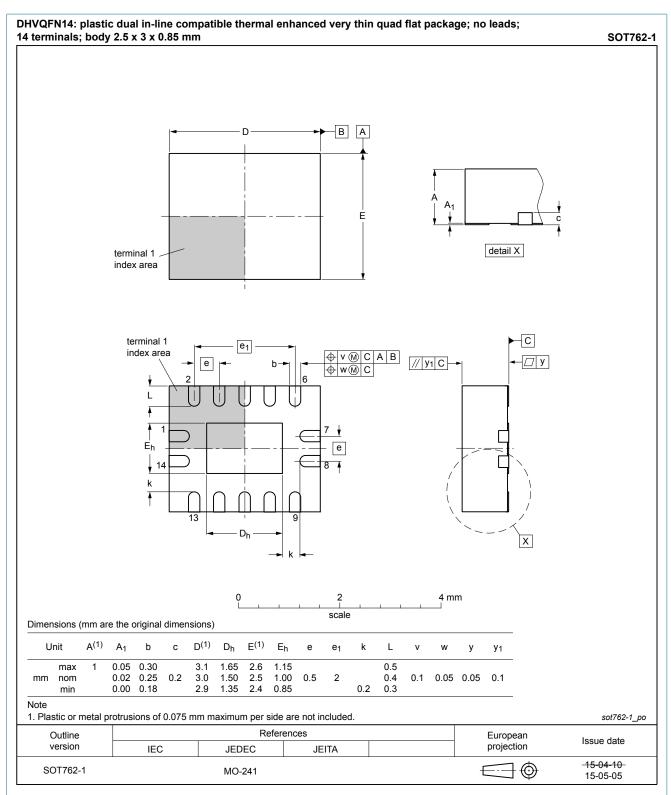


Fig. 10. Package outline SOT762-1 (DHVQFN14)

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12. Abbreviations

Table 9. Abbreviations

Acronym	Description		
CDM	Charged Device Model		
CMOS	Complementary Metal Oxide Semiconductor		
DUT	Device Under Test		
ESD	ElectroStatic Discharge		
НВМ	Human Body Model		
MM	Machine Model		
TTL	Transistor-Transistor Logic		

13. Revision history

Table 10. Revision history

table to the total and the tot						
Document ID	Release date	Data sheet status	Change notice	Supersedes		
74LVC30A v.2	20190315	Product data sheet	-	74LVC30A v.1		
Modifications:	Nexperia. • Legal texts have	 The format of this data sheet has been redesigned to comply with the identity guidelines of Nexperia. Legal texts have been adapted to the new company name where appropriate. Fig. 10: Package outline drawing SOT762-1 updated. 				
74LVC30A v.1	20140623	Product data sheet	-	-		

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14. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
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